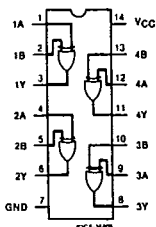


CD54/74AC86
CD54/74ACT86

T-43-21

Advance Information



Quad 2-Input Exclusive-OR Gate

Type Features:

- Buffered inputs
- Typical propagation delay:
3.2 ns @ $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$, $C_L = 50\text{ pF}$

FUNCTIONAL DIAGRAM & TERMINAL ASSIGNMENT

The RCA CD54/74AC86 and CD54/74ACT86 quad 2-input Exclusive-OR gates use the RCA ADVANCED CMOS technology. The CD74AC86 and CD74ACT86 are supplied in 14-lead dual-in-line plastic packages (E suffix) and in 14-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The CD54AC86 and CD54ACT86, available in chip form (H suffix), are operable over the -55 to +125°C temperature range.

Family Features:

- Exceeds 2-kV ESD Protection - MIL-STD-883, Method 3015
- SCR-Latchup-resistant CMOS process and circuit design
- Speed of bipolar FAST®/AS/S with significantly reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply.
- ±24-mA output drive current
 - Fanout to 15 FAST® ICs
 - Drives 50-ohm transmission lines

TRUTH TABLE

INPUTS		OUTPUT
nA	nB	nY
L	L	L
H	H	L
H	L	H
L	H	H

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MAXIMUM RATINGS, Absolute-Maximum Values:

- DC SUPPLY-VOLTAGE (V_{CC}) -0.5 to 6 V
- DC INPUT DIODE CURRENT, I_{IK} (for $V_I < -0.5\text{ V}$ or $V_I > V_{CC} + 0.5\text{ V}$) ±20 mA
- DC OUTPUT DIODE CURRENT, I_{OK} (for $V_O < -0.5\text{ V}$ or $V_O > V_{CC} + 0.5\text{ V}$) ±50 mA
- DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, I_O (for $V_O > -0.5\text{ V}$ or $V_O < V_{CC} + 0.5\text{ V}$) ±50 mA
- DC V_{CC} or GROUND CURRENT (I_{CC} or I_{GND}) ±100 mA*
- POWER DISSIPATION PER PACKAGE (P_D):
 - For $T_A = -55$ to $+100^\circ\text{C}$ (PACKAGE TYPE E) 500 mW
 - For $T_A = +100$ to $+125^\circ\text{C}$ (PACKAGE TYPE E) Derate Linearly at 8 mW/°C to 300 mW
 - For $T_A = -55$ to $+70^\circ\text{C}$ (PACKAGE TYPE M) 400 mW
 - For $T_A = +70$ to $+125^\circ\text{C}$ (PACKAGE TYPE M) Derate Linearly at 6 mW/°C to 70 mW
- OPERATING-TEMPERATURE RANGE (T_A): -55 to +125°C
- STORAGE TEMPERATURE (T_{STG}) -65 to +150°C
- LEAD TEMPERATURE (DURING SOLDERING):
 - At distance $1/16 \pm 1/32$ in. (1.59 ± 0.79 mm) from case for 10 s maximum +265°C
 - Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only +300°C

* For up to 4 outputs per device; add ±25 mA for each additional output.

9

Technical Data

T-43-21

CD54/74AC86
CD54/74ACT86

RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	LIMITS		UNITS
	MIN.	MAX.	
Supply-Voltage Range, V_{CC}^* : (For T_A = Full Package-Temperature Range) AC Types ACT Types	1.5	5.5	V
	4.5	5.5	V
DC Input or Output Voltage, V_i, V_o	0	V_{CC}	V
Operating Temperature, T_A :	-55	+125	°C
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)	0	50	ns/V
	0	20	ns/V
	0	10	ns/V
	0	10	ns/V

*Unless otherwise specified, all voltages are referenced to ground.

STATIC ELECTRICAL CHARACTERISTICS: AC Series

CHARACTERISTICS	TEST CONDITIONS		V_{CC} (V)	AMBIENT TEMPERATURE (T_A) - °C						UNITS	
				+25		-40 to +85		-55 to +125			
				MIN.	MAX.	MIN.	MAX.	MIN.	MAX.		
High-Level Input Voltage V_{IH}			1.5	1.2	—	1.2	—	1.2	—	V	
			3	2.1	—	2.1	—	2.1	—		
			5.5	3.85	—	3.85	—	3.85	—		
Low-Level Input Voltage V_{IL}			1.5	—	0.3	—	0.3	—	0.3	V	
			3	—	0.9	—	0.9	—	0.9		
			5.5	—	1.65	—	1.65	—	1.65		
High-Level Output Voltage V_{OH}	V_{IH} or V_{IL}	#, *	-0.05	1.5	1.4	—	1.4	—	1.4	—	V
			-0.05	3	2.9	—	2.9	—	2.9	—	
			-0.05	4.5	4.4	—	4.4	—	4.4	—	
			-4	3	2.58	—	2.48	—	2.4	—	
			-24	4.5	3.94	—	3.8	—	3.7	—	
			-75	5.5	—	—	3.85	—	—	—	
			-50	5.5	—	—	—	—	3.85	—	
Low-Level Output Voltage V_{OL}	V_{IH} or V_{IL}	#, *	0.05	1.5	—	0.1	—	0.1	—	0.1	V
			0.05	3	—	0.1	—	0.1	—	0.1	
			0.05	4.5	—	0.1	—	0.1	—	0.1	
			12	3	—	0.36	—	0.44	—	0.5	
			24	4.5	—	0.36	—	0.44	—	0.5	
			75	5.5	—	—	—	1.65	—	—	
			50	5.5	—	—	—	—	—	1.65	
Input Leakage Current I_i	V_{CC} or GND		5.5	—	±0.1	—	±1	—	±1	µA	
Quiescent Supply Current, SSI I_{CC}	V_{CC} or GND	0	5.5	—	4	—	40	—	80	µA	

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

CHARACTERISTICS	TEST CONDITIONS		V _{CC} (V)	AMBIENT TEMPERATURE (T _a) - °C						UNITS
				+25		-40 to +85		-55 to +125		
	V _I (V)	I _O (mA)		MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage V _{IH}			4.5 to 5.5	2	—	2	—	2	—	V
Low-Level Input Voltage V _{IL}			4.5 to 5.5	—	0.8	—	0.8	—	0.8	V
High-Level Output Voltage V _{OH}	V _{IH} or V _{IL} #, *	-0.05	4.5	4.4	—	4.4	—	4.4	—	V
		-24	4.5	3.94	—	3.8	—	3.7	—	
		-75	5.5	—	—	3.85	—	—	—	
		-50	5.5	—	—	—	—	3.85	—	
Low-Level Output Voltage V _{OL}	V _{IH} or V _{IL} #, *	0.05	4.5	—	0.1	—	0.1	—	0.1	V
		24	4.5	—	0.36	—	0.44	—	0.5	
		75	5.5	—	—	—	1.65	—	—	
		50	5.5	—	—	—	—	—	1.65	
Input Leakage Current I _I	V _{CC} or GND		5.5	—	±0.1	—	±1	—	±1	μA
Quiescent Supply Current, SSI I _{CC}	V _{CC} or GND	0	5.5	—	4	—	40	—	80	μA
Additional Quiescent Supply Current per Input Pin TTL Inputs High 1 Unit Load ΔI _{CC}	V _{CC} -2.1		4.5 to 5.5		2.4	—	2.8	—	3	mA

#Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.
*Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

ACT INPUT LOADING TABLE

INPUT	UNIT LOADS*
ALL	0.48

*Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25°C.

9

CD54/74AC86
CD54/74ACT86

SWITCHING CHARACTERISTICS: AC Series; $t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	V_{CC} (V)	AMBIENT TEMPERATURE (T_A) - °C				UNITS
			-40 to +85		-55 to +125		
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: Input to Outputs	t_{PLH} t_{PHL}	1.5 3.3* 5†	— 3.9 2.8	123 13.7 9.8	— 3.8 2.7	135 15.1 10.8	ns
Power Dissipation Capacitance	$C_{PD}\S$	—	57 Typ.		57 Typ.		pF
Input Capacitance	C_i	—	—	10	—	10	pF

SWITCHING CHARACTERISTICS: ACT Series; $t_r, t_f = 3 \text{ ns}$, $C_L = 50 \text{ pF}$

CHARACTERISTICS	SYMBOL	V_{CC} (V)	AMBIENT TEMPERATURE (T_A) - °C				UNITS
			-40 to +85		-55 to +125		
			MIN.	MAX.	MIN.	MAX.	
Propagation Delays: Input to Outputs	t_{PLH} t_{PHL}	5†	3.8	13.3	3.7	14.6	ns
Power Dissipation Capacitance	$C_{PD}\S$	—	57 Typ.		57 Typ.		pF
Input Capacitance	C_i	—	—	10	—	10	pF

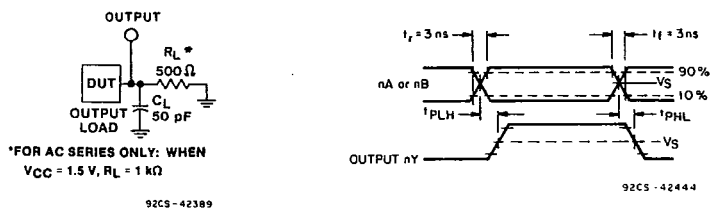
*3.3 V: min. is @ 3.6 V
max. is @ 3 V

†5 V: min. is @ 5.5 V
max. is @ 4.5 V

§ C_{PD} is used to determine the dynamic power consumption, per gate.

For AC series: $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$

For ACT series: $P_D = V_{CC}^2 f_i (C_{PD} + C_L) + V_{CC} \Delta I_{CC}$ where f_i = input frequency
 C_L = output load capacitance
 V_{CC} = supply voltage.



	CD54/74AC	CD54/74ACT
Input Level	V_{CC}	3 V
Input Switching Voltage, V_s	0.5 V_{CC}	1.5 V
Output Switching Voltage, V_s	0.5 V_{CC}	0.5 V_{CC}

Fig. 1 - Propagation delay times and test circuit.